

50V NPN PRE-BIASED (R1=R2) SMALL SIGNAL TRANSISTOR IN DFN1006

Product Summary

| Part Number | R1(NOM) | R2(NOM) | Marking |
|-------------|---------|---------|---------|
| DDTC144ELP | 47kΩ | 47kΩ | N6 |

Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (DDTA144ELP)
- Ultra-Small Leadless Surface Mount Package
- Ideally Suited for Automated Assembly Processes
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

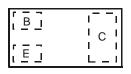
Mechanical Data

- Case: X1-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Marking Information
- Terminals: Finish NiPdAu
 Solderable per MIL-STD-202, Method 208@4
- Weight: 0.001 grams (Approximate)

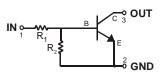




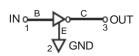
Bottom View



Top View Pin-Out



Device Symbol



Equivalent Inverter Circuit

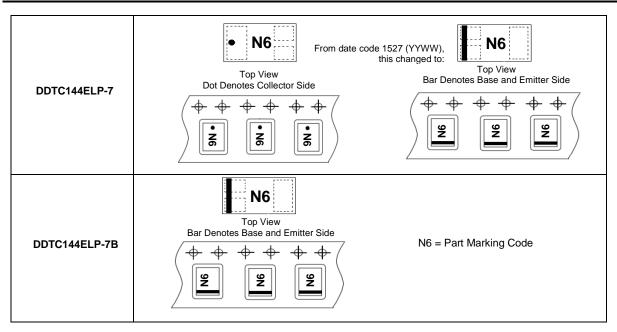
Ordering Information (Note 4)

| Part Number | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|---------------|---------|--------------------|-----------------|-------------------|
| DDTC144ELP-7 | N6 | 7 | 8 | 3,000 |
| DDTC144ELP-7B | N6 | 7 | 8 | 10,000 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information





Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|----------------|---------------------|------------|------|
| Supply Voltage | V _{CC} | 50 | V |
| Input Voltage | V _{IN} | -10 to +40 | V |
| Output Current | I _{C(MAX)} | 100 | mA |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|------------------------------------------------------|-----------------------------------|-------------|-------|
| Power Dissipation (Note 5) | P_{D} | 250 | mW |
| Power Deration above 25°C | P _{der} | 2 | mW/°C |
| Thermal Resistance, Junction to Ambient Air (Note 5) | $R_{	heta JA}$ | 500 | °C/W |
| Operation and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|----------------------------------------------|--------------------------------|------|-----|------|------|---------------------------------------------------------|
| Collector-Base Breakdown Voltage | BV _{CBO} | 50 | _ | _ | V | $I_C = 50\mu A, I_E = 0$ |
| Collector-Emitter Breakdown Voltage (Note 6) | BV _{CEO} | 50 | _ | _ | V | $I_C = 1.0 \text{mA}, I_B = 0$ |
| Collector-Base Cut Off Current | I _{CBO} | | | 0.5 | μΑ | $V_{CB} = 50V, I_{E} = 0$ |
| Input Voltage (Note 6) | V _{I(OFF)} | 0.5 | 1.2 | _ | V | $V_{CE} = 5V, I_{O} = 100\mu A$ |
| input voitage (Note 6) | V _{I(ON)} | _ | 1.6 | 3 |] | $V_{CE} = 0.3V, I_{O} = 2mA$ |
| Output Voltage (Note 6) | V _{O(ON)} | _ | _ | 0.3 | V | $I_0/I_1 = 10 \text{mA}/0.5 \text{mA}$ |
| Input Current | l _l | _ | _ | 0.18 | mA | $V_I = 5V$ |
| Output Current | I _{O(OFF)} | | | 0.5 | μΑ | $V_{CC} = 50V$, $V_I = 0V$ |
| DC Current Gain (Note 6) | G ₁ | 68 | _ | _ | _ | $V_0 = 5V, I_0 = 5mA$ |
| Input Resistance | R ₁ | 32.9 | 47 | 61.1 | kΩ | _ |
| Resistance Ratio | R ₂ /R ₁ | 0.8 | 1 | 1.2 | _ | _ |
| Transition Frequency (Note 7) | f⊤ | _ | 250 | _ | MHz | V _{CE} = 10V, I _E = 5mA, f = 100MHz |

Notes:

^{5.} For the device mounted on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady state condition. The entire exposed collector pad is attached to the heatsink.

6. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

7. Characteristics of transistor only.



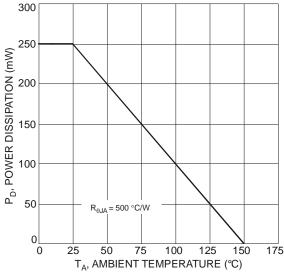


Fig. 1 Power Dissipation vs. Ambient Temperature

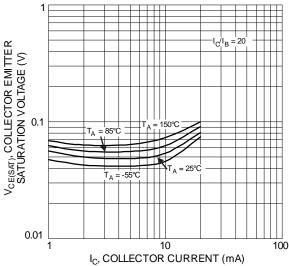
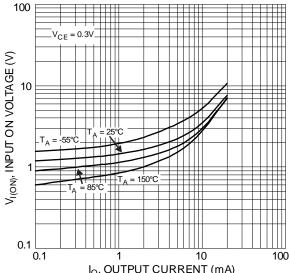


Fig. 3 Typical Collector Emitter Saturation Voltage vs. Collector Current



I_O, OUTPUT CURRENT (mA) Fig. 5 Typical Input ON Voltage vs. Output Current

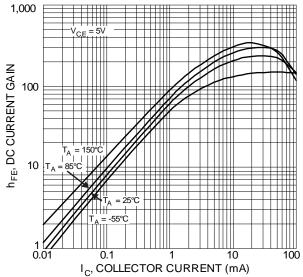
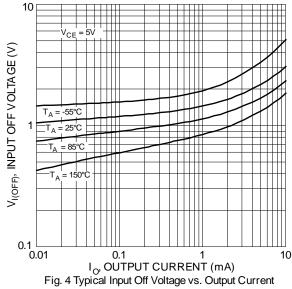


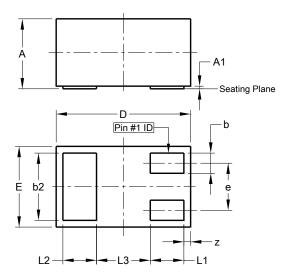
Fig. 2 Typical DC Current Gain vs. Collector Current





Package Outline Dimensions

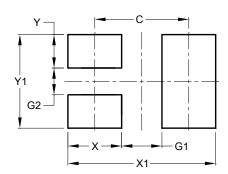
Please see http://www.diodes.com/package-outlines.html for the latest version.



| X1-DFN1006-3 | | | | |
|----------------------|------|-------|------|--|
| Dim | Min | Max | Тур | |
| Α | 0.47 | 0.53 | 0.50 | |
| A1 | 0.00 | 0.05 | 0.03 | |
| b | 0.10 | 0.20 | 0.15 | |
| b2 | 0.45 | 0.55 | 0.50 | |
| D | 0.95 | 1.075 | 1.00 | |
| E | 0.55 | 0.675 | 0.60 | |
| е | ı | - | 0.35 | |
| L1 | 0.20 | 0.30 | 0.25 | |
| L2 | 0.20 | 0.30 | 0.25 | |
| L3 | - | - | 0.40 | |
| z | 0.02 | 0.08 | 0.05 | |
| All Dimensions in mm | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 0.70 |
| G1 | 0.30 |
| G2 | 0.20 |
| Х | 0.40 |
| X1 | 1.10 |
| Y | 0.25 |
| Y1 | 0.70 |



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